NSN 5961-01-468-6625

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-468-6625 **Inclosure Material:** Glass **Overall Length:** 1.280 millimeters **Terminal Length:** 0.280 millimeters **Overall Width:** 0.384 millimeters **End Application:** E/ifscm controller **Mounting Facility Quantity: Mounting Method: Terminal Terminal Circle Diameter:** 0.384 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 base supply voltage and 60.0 forward voltage, peak **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Special Features:** Diode bridge controller **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No Fiig: A110a0